

HA-2520/883

Uncompensated, High Slew Rate Operational Amplifier

FN3735
Rev 3.00
October 11, 2004

The HA-2520/883 is a monolithic operational amplifier which delivers an unsurpassed combination of specifications for slew rate, bandwidth and settling time. This dielectrically isolated amplifier is designed for closed loop gains of 3 or greater without external compensation. In addition, this high performance component also provides low offset current and high input impedance.

The 100V/μs (min) slew rate and fast settling time of this amplifier make it ideal for pulse amplification and data acquisition designs. To insure compliance with slew rate and transient response specifications, the device is 100% tested for AC performance characteristics over full temperature. This device is a valuable component for RF and video circuitry requiring wideband operation. For accurate signal conditioning designs, the HA-2520/883's superior dynamic specifications are complemented by 25nA (max) offset current and offset voltage adjust capability.

Part Number Information

PART NUMBER	TEMP. RANGE (°C)	PACKAGE	PKG. NO.
HA2-2520/883	-55°C to +125°C	8 Pin Can	T8.C

Applications

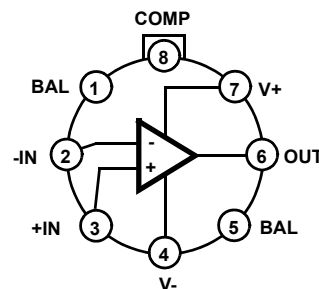
- Data Acquisition Systems
- RF Amplifiers
- Video Amplifiers
- Signal Generators
- Pulse Amplification

Features

- This Circuit is Processed in Accordance to MIL-STD-883 and is Fully Conformant Under the Provisions of Paragraph 1.2.1.
- High Slew Rate 100V/μs (Min)
120V/μs (Min)
- Wide Power Bandwidth 1.5MHz (Min)
- Wide Gain Bandwidth. 10MHz (Min)
20MHz (Typ)
- High Input Impedance 50MΩ (Min)
100MΩ (Typ)
- Low Offset Current 25nA (Min)
10nA (Typ)
- Fast Settling (0.1% of 10V Step) 200ns (Typ)
- Low Quiescent Supply Current 6mA (Max)

Pinout

**HA-2520/883
(METAL CAN)**
TOP VIEW



Absolute Maximum Ratings

Voltage Between V+ and V- Terminals40V
 Differential Input Voltage15V
 Voltage at Either Input Terminal V+ to V-
 Peak Output Current 50mA
 Junction Temperature+175°C
 Storage Temperature Range -65°C to +150°C
 ESD Rating<2000V
 Lead Temperature (Soldering 10s)+300°C

Thermal Information

Thermal Resistance θ_{JA} θ_{JC}
 Metal Can Package 160°C/W 75°C/W
 Package Power Dissipation Limit at +75°C for $T_J \leq +175^\circ\text{C}$
 Metal Can Package 625mW
 Package Power Dissipation Derating Factor Above +75°C
 Metal Can Package 6.3mW/°C

Operating Conditions

Operating Temperature Range -55°C to +125°C
 Operating Supply Voltage $\pm 15\text{V}$

$V_{INCM} \leq 1/2 (V+ - V-)$
 $R_L \geq 2\text{k}\Omega$

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. θ_{JA} is measured with the component mounted on a low effective thermal conductivity test board in free air. See Tech Brief TB379 for details.

TABLE 1. DC ELECTRICAL PERFORMANCE CHARACTERISTICS

Device Tested at: $V_{SUPPLY} = \pm 15\text{V}$, $R_{SOURCE} = 100\Omega$, $R_{LOAD} = 500\text{k}\Omega$, $V_{OUT} = 0\text{V}$, Unless Otherwise Specified.

PARAMETERS	SYMBOL	CONDITIONS	GROUP A SUBGROUPS	TEMPERATURE	HA-2520/883		UNITS
					MIN	MAX	
Input Offset Voltage	V_{IO}	$V_{CM} = 0\text{V}$	1	+25°C	-8	8	mV
			2, 3	+125°C, -55°C	-10	10	mV
Input Bias Current	+ I_B	$V_{CM} = 0\text{V}$, $+R_S = 100\text{k}\Omega$, $-R_S = 100\Omega$	1	+25°C	-200	200	nA
			2, 3	+125°C, -55°C	-400	400	nA
	- I_B	$V_{CM} = 0\text{V}$, $+R_S = 100\Omega$, $-R_S = 100\text{k}\Omega$	1	+25°C	-200	200	nA
			2, 3	+125°C, -55°C	-400	400	nA
Input Offset Current	I_{IO}	$V_{CM} = 0\text{V}$, $+R_S = 100\text{k}\Omega$, $-R_S = 100\text{k}\Omega$	1	+25°C	-25	25	nA
			2, 3	+125°C, -55°C	-50	50	nA
Common Mode Range	+CMR	$V+ = 5\text{V}$, $V- = -25\text{V}$	1	+25°C	+10	-	V
			2, 3	+125°C, -55°C	+10	-	V
	-CMR	$V+ = 25\text{V}$, $V- = -5\text{V}$	1	+25°C	-	-10	V
			2, 3	+125°C, -55°C	-	-10	V
Large Signal Voltage Gain	+ A_{VOL}	$V_{OUT} = 0\text{V}$ and +10V, $R_L = 2\text{k}\Omega$	4	+25°C	10	-	kV/V
			5, 6	+125°C, -55°C	7.5	-	kV/V
	- A_{VOL}	$V_{OUT} = 0\text{V}$ and -10V, $R_L = 2\text{k}\Omega$	4	+25°C	10	-	kV/V
			5, 6	+125°C, -55°C	7.5	-	kV/V
Common Mode Rejection Ratio	+CMRR	$\Delta V_{CM} = +10\text{V}$, $V+ = +5\text{V}$, $V- = -25\text{V}$, $V_{OUT} = -10\text{V}$	1	+25°C	80	-	dB
			2, 3	+125°C, -55°C	80	-	dB
	-CMRR	$\Delta V_{CM} = -10\text{V}$, $V+ = +25\text{V}$, $V- = -5\text{V}$, $V_{OUT} = +10\text{V}$	1	+25°C	80	-	dB
			2, 3	+125°C, -55°C	80	-	dB
Output Voltage Swing	+ V_{OUT}	$R_L = 2\text{k}\Omega$	4	+25°C	10	-	V
			5, 6	+125°C, -55°C	10	-	V
	- V_{OUT}	$R_L = 2\text{k}\Omega$	4	+25°C	-	-10	V
			5, 6	+125°C, -55°C	-	-10	V

TABLE 1. DC ELECTRICAL PERFORMANCE CHARACTERISTICS (Continued)Device Tested at: $V_{\text{SUPPLY}} = \pm 15\text{V}$, $R_{\text{SOURCE}} = 100\Omega$, $R_{\text{LOAD}} = 500\text{k}\Omega$, $V_{\text{OUT}} = 0\text{V}$, Unless Otherwise Specified.

PARAMETERS	SYMBOL	CONDITIONS	GROUP A SUBGROUPS	TEMPERATURE	HA-2520/883		UNITS
					MIN	MAX	
Output Current	+I _{OUT}	V _{OUT} = -10V	4	+25°C	10	-	mA
			5, 6	+125°C, -55°C	7.5	-	mA
	-I _{OUT}	V _{OUT} = +10V	4	+25°C	-	-10	mA
			5, 6	+125°C, -55°C	-	-7.5	mA
Quiescent Power Supply Current	+I _{CC}	V _{OUT} = 0V, I _{OUT} = 0mA	1	+25°C	-	6	mA
			2, 3	+125°C, -55°C	-	6.5	mA
	-I _{CC}	V _{OUT} = 0V, I _{OUT} = 0mA	1	+25°C	-6	-	mA
			2, 3	+125°C, -55°C	-6.5	-	mA
Power Supply Rejection Ratio	+PSRR	$\Delta V_{\text{SUP}} = 10\text{V}$, V+ = +20V, V- = -15V, V+ = +10V, V- = -15V	1	+25°C	80	-	dB
			2, 3	+125°C, -55°C	80	-	dB
	-PSRR	$\Delta V_{\text{SUP}} = 10\text{V}$, V+ = +15V, V- = -20V, V+ = +15V, V- = -10V	1	+25°C	80	-	dB
			2, 3	+125°C, -55°C	80	-	dB
Offset Voltage Adjustment	+V _{IOAdj}	Note 1	1	+25°C	V _{IO} -1	-	mV
			2, 3	+125°C, -55°C	V _{IO} -1	-	mV
	-V _{IOAdj}	Note 1	1	+25°C	V _{IO} +1	-	mV
			2, 3	+125°C, -55°C	V _{IO} +1	-	mV

NOTE:

2. Offset adjustment range is $[V_{\text{IO}}(\text{Measured}) \pm 1\text{mV}]$ minimum referred to output. This test is for functionality only to assure adjustment through 0V.

TABLE 2. AC ELECTRICAL PERFORMANCE CHARACTERISTICSDevice Tested at: $V_{\text{SUPPLY}} = \pm 15\text{V}$, $R_{\text{SOURCE}} = 50\Omega$, $R_{\text{LOAD}} = 2\text{k}\Omega$, $C_{\text{LOAD}} = 50\text{pF}$, $A_{\text{VCL}} = +3\text{V/V}$, Unless Otherwise Specified.

PARAMETERS	SYMBOL	CONDITIONS	GROUP A SUBGROUPS	TEMPERATURE	HA-2520/883		UNITS
					MIN	MAX	
Slew Rate	+SR	V _{OUT} = -5V to +5V, $25\% \leq +\text{SR} \leq 75\%$	7	+25°C	100	-	V/ μs
			8A, 8B	+125°C, -55°C	84	-	V/ μs
	-SR	V _{OUT} = +5V to -5V, $75\% \geq -\text{SR} \geq 25\%$	7	+25°C	100	-	V/ μs
			8A, 8B	+125°C, -55°C	84	-	V/ μs
Rise and Fall Time	T _R	V _{OUT} = 0 to +200mV, $10\% \leq T_{\text{R}} \leq 90\%$	7	+25°C	-	50	ns
			8A, 8B	+125°C, -55°C	-	55	ns
	T _F	V _{OUT} = 0 to -200mV, $10\% \leq T_{\text{F}} \leq 90\%$	7	+25°C	-	50	ns
			8A, 8B	+125°C, -55°C	-	55	ns
Overshoot	+OS	V _{OUT} = 0 to +200mV	7	+25°C	-	40	%
			8A, 8B	+125°C, -55°C	-	45	%
	-OS	V _{OUT} = 0 to -200mV	7	+25°C	-	40	%
			8A, 8B	+125°C, -55°C	-	45	%

TABLE 3. ELECTRICAL PERFORMANCE CHARACTERISTICS

Device Characterized at: $V_{SUPPLY} = \pm 15V$, $R_{LOAD} = 2k\Omega$, $C_{LOAD} = 50pF$, $A_V \geq 3$, $C_{COMP} = 0pF$, Unless Otherwise Specified.

PARAMETERS	SYMBOL	CONDITIONS	NOTES	TEMPERATURE	HA-2520/883		UNITS
					MIN	MAX	
Differential Input Resistance	R_{IN}	$V_{CM} = 0V$	1	+25°C	50	-	$M\Omega$
Full Power Bandwidth	GBWP	$V_O = 200mV$, $f_O = 10kHz$	1	+25°C	10	-	MHz
		$V_O = 200mV$, $f_O = 1MHz$	1	+25°C	10	-	MHz
Full Power Bandwidth	FPBW	$V_{PEAK} = 10V$	1, 2	+25°C	1.6	-	MHz
Minimum Closed Loop Stable Gain	CLSG	$R_L = 2k\Omega$, $C_L = 50pF$	1	-55°C to +125°C	+3	-	V/V
Quiescent Power Consumption	PC	$V_{OUT} = 0V$, $I_{OUT} = 0mA$	1, 3	-55°C to +125°C	-	195	mW

NOTES:

- Parameters listed in Table 3 are controlled via design or process parameters and are not directly tested at final production. These parameters are lab characterized upon initial design release, or upon design changes. These parameters are guaranteed by characterization based upon data from multiple production runs which reflect lot to lot and within lot variation.
- Full Power Bandwidth guarantee based on Slew Rate measurement using $FPBW = \text{Slew Rate} / (2\pi V_{PEAK})$.
- Quiescent Power Consumption based upon Quiescent Supply Current test maximum. (No load on outputs.)

TABLE 4. ELECTRICAL TEST REQUIREMENTS

MIL-STD-883 TEST REQUIREMENTS	SUBGROUPS (SEE TABLES 1 AND 2)
Interim Electrical Parameters (Pre Burn-In)	1
Final Electrical Test Parameters	1 (Note 4), 2, 3, 4, 5, 6, 7, 8A, 8B
Group A Test Requirements	1, 2, 3, 4, 5, 6, 7, 8A, 8B
Groups C and D Endpoints	1

NOTE:

- PDA applies to Subgroup 1 only.

Die Characteristics

DIE DIMENSIONS:

67 x 57 x 19 mils $\pm$ 1 mils
 1700 x 1440 x 483 μ m $\pm$ 25.4 μ m

METALLIZATION:

Type: Al, 1% Cu
 Thickness: 16kÅ $\pm$ 2kÅ

GLASSIVATION:

Type: Nitride (Si₃N₄) over Silox (SiO₂, 5% Phos.)
 Silox Thickness: 12kÅ $\pm$ 2kÅ
 Nitride Thickness: 3.5kÅ $\pm$ 1.5kÅ

WORST CASE CURRENT DENSITY:

0.26×10^5 A/cm²

SUBSTRATE POTENTIAL (Powered Up):

Unbiased

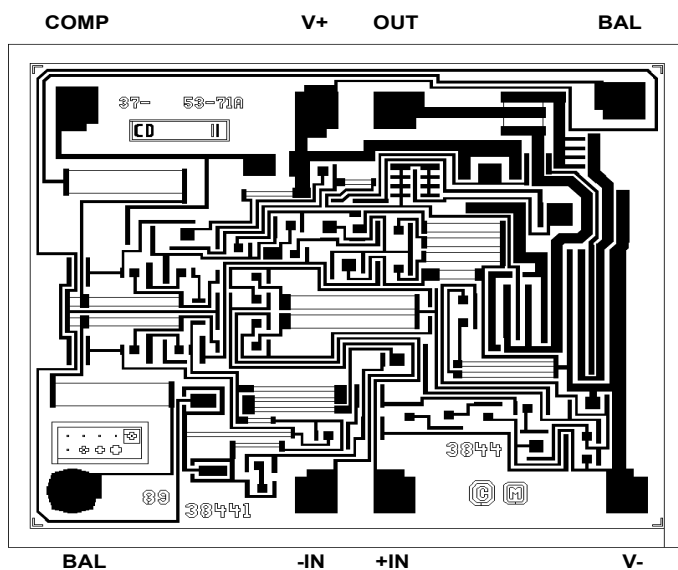
TRANSISTOR COUNT:

HA-2520/883: 40

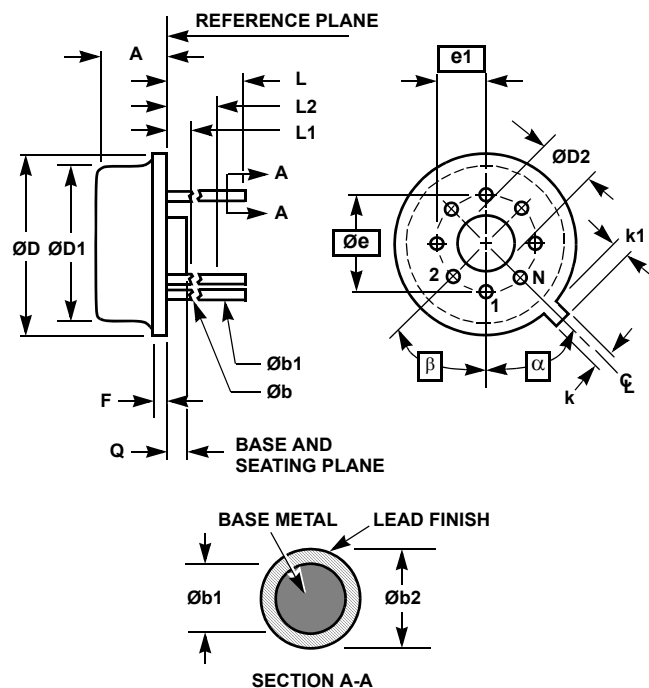
PROCESS:

Bipolar Dielectric Isolation

Metallization Mask Layout



Metal Can Packages (Can)



NOTES:

1. (All leads) Øb applies between L1 and L2. Øb1 applies between L2 and 0.500 from the reference plane. Diameter is uncontrolled in L1 and beyond 0.500 from the reference plane.
2. Measured from maximum diameter of the product.
3. α is the basic spacing from the centerline of the tab to terminal 1 and β is the basic spacing of each lead or lead position (N - 1 places) from α , looking at the bottom of the package.
4. N is the maximum number of terminal positions.
5. Dimensioning and tolerancing per ANSI Y14.5M - 1982.
6. Controlling dimension: INCH.

T8.C MIL-STD-1835 MACY1-X8 (A1) 8 LEAD METAL CAN PACKAGE

SYMBOL	INCHES		MILLIMETERS		NOTES
	MIN	MAX	MIN	MAX	
A	0.165	0.185	4.19	4.70	-
Øb	0.016	0.019	0.41	0.48	1
Øb1	0.016	0.021	0.41	0.53	1
Øb2	0.016	0.024	0.41	0.61	-
ØD	0.335	0.375	8.51	9.40	-
ØD1	0.305	0.335	7.75	8.51	-
ØD2	0.110	0.160	2.79	4.06	-
e	0.200 BSC		5.08 BSC		-
e1	0.100 BSC		2.54 BSC		-
F	-	0.040	-	1.02	-
k	0.027	0.034	0.69	0.86	-
k1	0.027	0.045	0.69	1.14	2
L	0.500	0.750	12.70	19.05	1
L1	-	0.050	-	1.27	1
L2	0.250	-	6.35	-	1
Q	0.010	0.045	0.25	1.14	-
α	45° BSC		45° BSC		3
β	45° BSC		45° BSC		3
N	8		8		4

Rev. 0 5/18/94

© Copyright Intersil Americas LLC 2002-2004. All Rights Reserved.
All trademarks and registered trademarks are the property of their respective owners.

For additional products, see www.intersil.com/en/products.html

Intersil products are manufactured, assembled and tested utilizing ISO9001 quality systems as noted in the quality certifications found at www.intersil.com/en/support/qualandreliability.html

Intersil products are sold by description only. Intersil may modify the circuit design and/or specifications of products at any time without notice, provided that such modification does not, in Intersil's sole judgment, affect the form, fit or function of the product. Accordingly, the reader is cautioned to verify that datasheets are current before placing orders. Information furnished by Intersil is believed to be accurate and reliable. However, no responsibility is assumed by Intersil or its subsidiaries for its use; nor for any infringements of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of Intersil or its subsidiaries.

For information regarding Intersil Corporation and its products, see www.intersil.com